TOSHIBA Field Effect Transistor Silicon N Channel Junction Type

2SK246

For Constant Current, Impedance Converter and DC-AC High Input Impedance Amplifier Circuit Applications

• High breakdown voltage: $V_{\rm GDS} = -50 \text{ V}$

• High input impedance: $I_{GSS} = -1$ nA (max) ($V_{GS} = -30$ V)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Gate-drain voltage	V_{GDS}	-50	V
Gate current	IG	10	mA
Drain power dissipation	P _D	300	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	−55~125	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the

absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling

Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

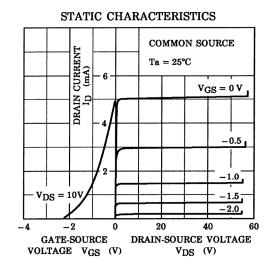
1. SOURCE 2. GATE 3. DRAIN JEDEC TO-92 JEITA SC-43 TOSHIBA 2-5F1C

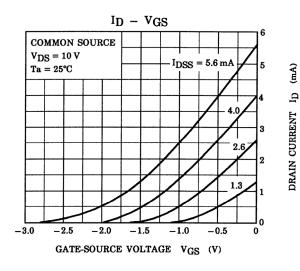
Weight: 0.21 g (typ.)

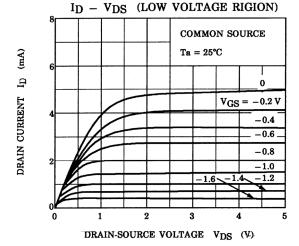
Electrical Characteristics (Ta = 25°C)

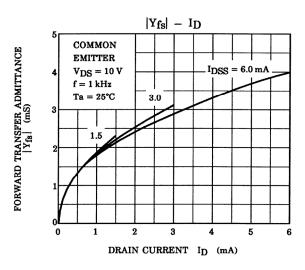
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate cut-off current	I _{GSS}	$V_{GS} = -30 \text{ V}, V_{DS} = 0$	_	_	-1.0	nA
Gate-drain breakdown voltage	V (BR) GDS	$V_{DS} = 0$, $I_G = -100 \mu A$	-50	_	_	V
Drain current	I _{DSS} (Note)	V _{DS} = 10 V, V _{GS} = 0	1.2		14	mA
Gate-source cut-off voltage	V _{GS} (OFF)	$V_{DS} = 10 \text{ V}, I_D = 0.1 \mu\text{A}$	-0.7	_	-6.0	V
Forward transfer admittance	Y _{fs}	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ kHz}$	1.5	_	_	mS
Input capacitance	C _{iss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$		9.0	_	pF
Reverse transfer capacitance	C _{rss}	$V_{DG} = 10 \text{ V}, I_D = 0, f = 1 \text{ MHz}$	_	2.5	_	pF

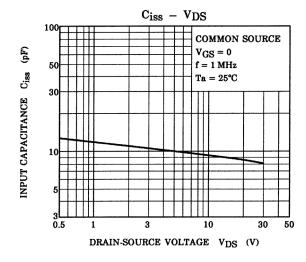
Note: IDSS classification Y: 1.2~3.0 mA, GR: 2.6~6.5 mA, BL: 6~14 mA

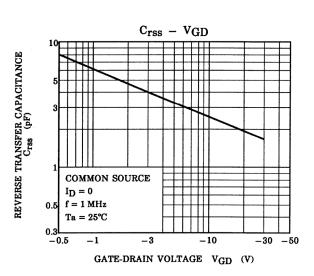


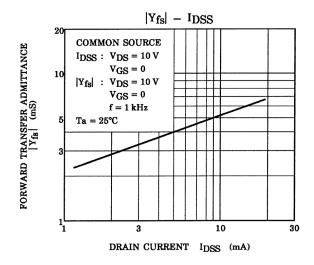


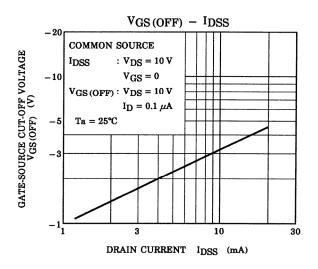


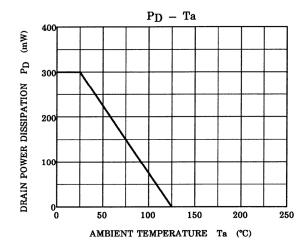












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20070701-EN GENERAL

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